TOSHIBA TA8136S

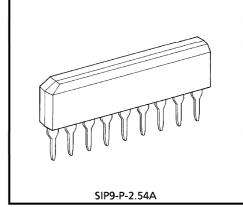
TOSHIBA BIPOLAR LINEAR INTEGRATED CIRCUIT SILICON MONOLITHIC

TA8136S

RADIO CONTROL TRANSMITTER IC

The TA8136S is designed for a 1 chip transmitter IC including pulse generator, duty control mixer, carrier oscillator, and RF power amplifier.

This IC has 7 control modes by combination of external switches (SW1 and SW2). A modulation frequency (pulse wave) is set arbitrarily by capacitance C1, resistance R1 and R2.

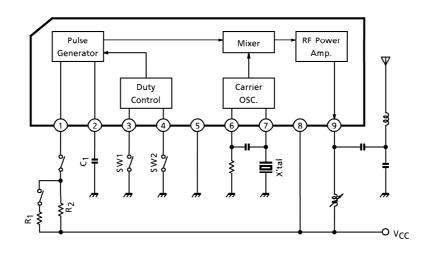


Weight: 0.92g (Typ.)

FEATURES

- Very few external parts
- Square wave frequency can be freely set.
- Square wave duty cycle can be controlled keeping fixed frequency.
- Wide supply voltage range : $V_{CC(opr)} = 6 \sim 11V$ (Recommended $V_{CC} = 9V$)

BLOCK DIAGRAM



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MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Supply Voltage	VCC	12	V
Power Dissipation	P _D (Note)	600	mW
Operating Temperature	T _{opr}	- 25∼75	°C
Storage Temperature	T _{stg}	- 55∼150	°C

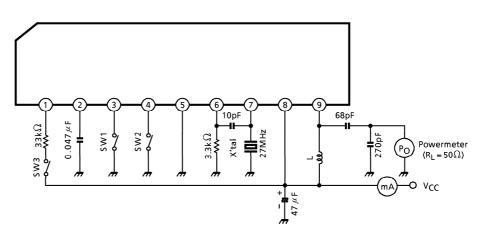
(Note) Derated above 25°C in the proportion of $4.8 \, \text{mW} \, / \, ^{\circ}\text{C}.$

ELECTRICAL CHARACTERISTICS (Unless otherwise specified, Ta = 25°C, V_{CC} = 9V, f_{OSC} = 27MHz)

CHARACTERISTIC	SYMBOL	TEST CIR- CUIT	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
	^I CC (1)		A Mode	-	20	27	
Supply Current	^I CC (2)	1	B Mode	-	22	_	mΑ
	¹ CC (3)		C Mode	-	18	_	
Transmitter Output	PO (1)	1	f _{OSC} = 27MHz SW3 : OFF	16	30	_	mW
Power	P _O (2)	2	f _{OSC} = 40MkHz (Note)	_	30	_	11100
Modulation Frequency	fm	3	A, B, C Mode	_	2.3	_	kHz

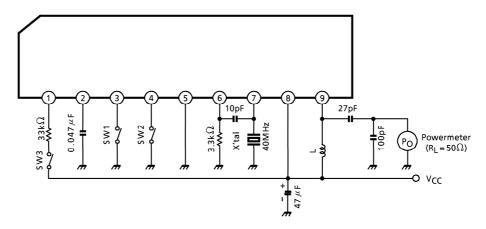
A Mode→SW1, SW2 : OFF B Mode→SW1 : ON, SW2 : OFF C Mode→SW1 : OFF, SW2 : ON (Note) Non Moduration Mode

TEST CIRCUIT 1



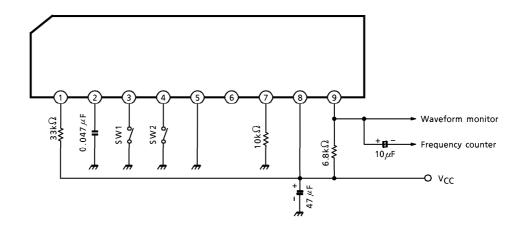
L: KY-6008 (Mitsumi) 10 1/2T, φ0.5mm UEW Bobbin with Ferrite Core

TEST CIRCUIT 2

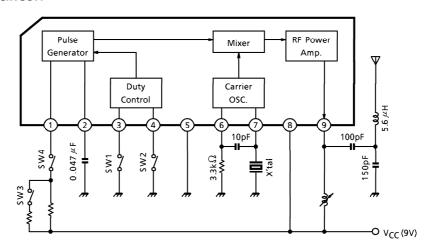


L : KY-6008 (Mitsumi) 10 1/2T, ϕ 0.5mm UEW Bobbin with Ferrite Core

TEST CIRCUIT 3



27MHZ APPLICATION CIRCUIT



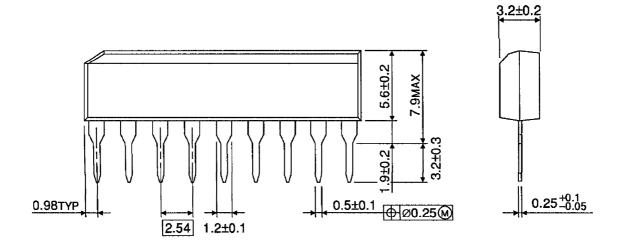
TRANSMITTER OUTPUT WAVE FORM

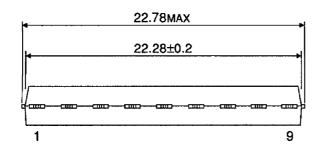
SW4	SW1	SW2	SW3 OFF	SW3 ON	DUTY CYCLE (%)
OFF	_	_			Non-Modulation Mode
ON	OFF	OFF	1/Freq.1	1/Freq.2	50
	ON	OFF			75
	OFF	ON			25

(Freq.1<Freq.2)

OUTLINE DRAWING

SIP9-P-2.54A Unit: mm





Weight: 0.92g (Typ.)